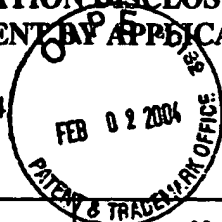


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INFORMATION DISCLOSURE
STATEMENT BY APPLICANT

Sheet 1 of 4



Application Number.: 10/732,951
 Filing Date: December 11, 2003
 First Named Inventor: Toshiharu Furukawa
 Art Unit: Unassigned 2826
 Examiner Name: Unassigned Pert
 Attorney Docket Number.: ROC920030269US1

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Document Number Number - Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns or Lines Where Relevant Passages or Figs. Appear
EP		US - 6,423,583 B1	07-23-2002	Avouris et al.	
EP		US - 6,515,325 B1	02-04-2003	Farnworth et al.	
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		US -			
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Examiner Initials	Cite No. ¹	Foreign Patent Document Country ³ - Number ⁴ - Kind Code ⁵ Code (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns or Lines Where Relevant Passages or Figs. Appear	T ⁶

Examiner Signature	<u>Eva Pert</u>	Date Considered	<u>9/16/05</u>
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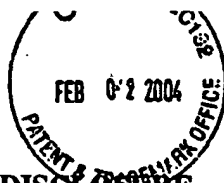
¹ Applicant's unique citation designation number (optional). ² See Kind Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3).

⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language translation is attached.

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**INFORMATION DISCLOSURE
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Sheet 2 of 4



Application Number.: 10/732,951
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 Art Unit: Unassigned 2826
 Examiner Name: Unassigned Per +
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OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

Examiner Initials	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and or country where published.	T ²
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Examiner Signature	<u>Evra Rut</u>	Date Considered	<u>9/11/05</u>
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**INFORMATION DISCLOSURE
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Sheet 3 of 4



Application Number.: 10/732,951
 Filing Date: December 11, 2003
 First Named Inventor: Toshiharu Furukawa
 Art Unit: Unassigned 2826
 Examiner Name: Unassigned Pert
 Attorney Docket Number.: ROC920030269US1

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

Examiner Initials	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and or country where published.	T ²
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Examiner Signature	<u>Evan Pert</u>	Date Considered	<u>9-18-05</u>
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 CLOSURE

Application Number.: 10/732,951
Filing Date: December 11, 2003
First Named Inventor: Toshiharu Furukawa
Art Unit: Unassigned
Examiner Name: Unassigned
Attorney Docket Number.: ROC920030269US1

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

[illegible]

Examiner Signature	Gwenbert	Date Considered	9/16-05
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